

	Type	Hits	Search Text	DBs
1	IS&R	8	((("6627502") or ("5905293") or ("5648287") or ("6136636"))).PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
2	IS&R	6	((("5930617") or ("5710054") or ("5759885"))).PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
3	BRS	11758	"438"/\$.ccls. and (MOS adj transistors)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
4	BRS	753	S3 and (shallow adj junctions)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
5	BRS	1	S4 and (doped adj polysilicon adj sidewalls)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
6	BRS	45	S4 and (etch adj stop adj layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
7	BRS	0	S4 and ((etch adj stop adj layer) and (temporary adj sidewall))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
8	BRS	2	S4 and (temporary adj sidewall)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
9	BRS	0	S4 and ((temporary adj sidewall) and (etch adj stop adj layre))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
10	BRS	0	S4 and (temporary adj sidewall) and (etch adj stop adj layre)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Type	Hits	Search Text	DBs
11	BRS	0	S4 and (temporary adj sidewall) and (etch adj stop adj layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
12	BRS	0	S6 and (temporary adj sidewall)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
13	BRS	38	S6 and sidewall	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB